August 2000

(Typical unless otherwise stated)

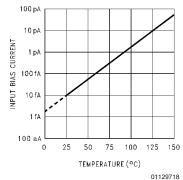
- Low offset voltage: 150 µV
- Operates from 4.5V to 15V single supply
- Ultra low input bias current: 10 fA
- Output swing to within 20 mV of supply rail, 100k load
- Input common-mode range includes V⁻
- High voltage gain: 130 dB
- Improved latchup immunity

Applications

- Instrumentation amplifier
- Photodiode and infrared detector preamplifier
- Transducer amplifiers
- Medical instrumentation
- D/A converter
- Charge amplifier for piezoelectric transducers

Input Bias Current vs Temperature







LMC6082 Precision CMOS Dual Operational Amplifier **General Description** Features

The LMC6082 is a precision dual low offset voltage operational amplifier, capable of single supply operation. Performance characteristics include ultra low input bias current, high voltage gain, rail-to-rail output swing, and an input common mode voltage range that includes ground. These features, plus its low offset voltage, make the LMC6082 ideally suited for precision circuit applications.

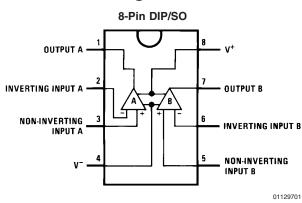
Other applications using the LMC6082 include precision fullwave rectifiers, integrators, references, and sample-andhold circuits.

This device is built with National's advanced Double-Poly Silicon-Gate CMOS process.

For designs with more critical power demands, see the LMC6062 precision dual micropower operational amplifier.

PATENT PENDING

Connection Diagram



Top View

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Differential Input Voltage	±Supply Voltage
Voltage at Input/Output Pin	(V ⁺) +0.3V,
	(V ⁻) –0.3V
Supply Voltage (V ⁺ - V ⁻)	16V
Output Short Circuit to V ⁺	(Note 11)
Output Short Circuit to V ⁻	(Note 2)
Lead Temperature	
(Soldering, 10 Sec.)	260°C
Storage Temp. Range	–65°C to +150°C
Junction Temperature	150°C
ESD Tolerance (Note 4)	2 kV
Current at Input Pin	±10 mA

Current at Output Pin	±30 mA
Current at Power Supply Pin	40 mA
Power Dissipation	(Note 3)

Operating Ratings (Note 1)

Temperature Range	
LMC6082AM	$-55^{\circ}C \le T_{J} \le$
	+125°C
LMC6082AI, LMC6082I	$-40^{\circ}C \le T_{J} \le +85^{\circ}C$
Supply Voltage	$4.5V \leq V^+ \leq 15.5V$
Thermal Resistance (θ_{JA}) (Note	
12)	
8-Pin Molded DIP	115°C/W
8-Pin SO	193°C/W
Power Dissipation	(Note 10)

DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$. **Boldface** limits apply at the temperature extremes. V⁺ = 5V, V⁻ = 0V, V_{CM} = 1.5V, V_O = 2.5V and R_L > 1M unless otherwise specified.

				Тур	LMC6082AM	LMC6082AI	LMC6082I	
Symbol	Parameter	Cond	itions	(Note 5)	Limit	Limit	Limit	Units
					(Note 6)	(Note 6)	(Note 6)	
Vos	Input Offset Voltage			150	350	350	800	μV
					1000	800	1300	Max
TCVos	Input Offset Voltage			1.0				µV/°C
	Average Drift							
I _B	Input Bias Current			0.010				pА
					100	4	4	Max
I _{os}	Input Offset Current			0.005				pА
					100	2	2	Max
R _{IN}	Input Resistance			>10				Tera Ω
CMRR	Common Mode	$0V \le V_{CM} \le T$	12.0V	85	75	75	66	dB
	Rejection Ratio	V ⁺ = 15V			72	72	63	Min
+PSRR	Positive Power Supply	$5V \le V^+ \le 15$	V	85	75	75	66	dB
	Rejection Ratio	$V_{O} = 2.5V$			72	72	63	Min
-PSRR	Negative Power Supply	$0V \le V^- \le -1$	0V	94	84	84	74	dB
	Rejection Ratio				81	81	71	Min
V _{CM}	Input Common-Mode	$V^+ = 5V$ and	15V	-0.4	-0.1	-0.1	-0.1	V
	Voltage Range	for CMRR \geq	60 dB		0	0	0	Max
				V ⁺ – 1.9	V ⁺ – 2.3	V ⁺ – 2.3	V ⁺ – 2.3	V
					V ⁺ – 2.6	V⁺ – 2.5	V+ – 2.5	Min
A _V	Large Signal	$R_L = 2 k\Omega$	Sourcing	1400	400	400	300	V/mV
	Voltage Gain	(Note 7)			300	300	200	Min
			Sinking	350	180	180	90	V/mV
					70	100	60	Min
		$R_L = 600\Omega$	Sourcing	1200	400	400	200	V/mV
		(Note 7)			150	150	80	Min
			Sinking	150	100	100	70	V/mV
					35	50	35	Min

DC Electrical Characteristics (Continued) Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}$ C. **Boldface** limits apply at the temperature extremes. V⁺ = 5V, V⁻ = 0V, V_{CM} = 1.5V, V_O = 2.5V and R_L > 1M unless otherwise specified.

			Тур	LMC6082AM	LMC6082AI	LMC6082I	
Symbol	Parameter	Conditions	(Note 5)	Limit	Limit	Limit	Units
				(Note 6)	(Note 6)	(Note 6)	
/ ₀	Output Swing	V ⁺ = 5V	4.87	4.80	4.80	4.75	V
		$R_L = 2 \ k\Omega$ to 2.5V		4.70	4.73	4.67	Min
			0.10	0.13	0.13	0.20	V
				0.19	0.17	0.24	Max
		V ⁺ = 5V	4.61	4.50	4.50	4.40	V
		$R_L = 600\Omega$ to 2.5V		4.24	4.31	4.21	Min
			0.30	0.40	0.40	0.50	V
				0.63	0.50	0.63	Мах
		V ⁺ = 15V	14.63	14.50	14.50	14.37	V
		$R_L = 2 \ k\Omega$ to 7.5V		14.30	14.34	14.25	Min
			0.26	0.35	0.35	0.44	V
				0.48	0.45	0.56	Мах
		V ⁺ = 15V	13.90	13.35	13.35	12.92	V
		$R_L = 600\Omega$ to 7.5V		12.80	12.86	12.44	Min
			0.79	1.16	1.16	1.33	V
				1.42	1.32	1.58	Мах
0	Output Current	Sourcing, V _O = 0V	22	16	16	13	mA
	V ⁺ = 5V			8	10	8	Min
		Sinking, V _O = 5V	21	16	16	13	mA
				11	13	10	Min
0	Output Current	Sourcing, V _O = 0V	30	28	28	23	mA
	V ⁺ = 15V			18	22	18	Min
		Sinking, V _O = 13V	34	28	28	23	mA
		(Note 11)		19	22	18	Min
s	Supply Current	Both Amplifiers	0.9	1.5	1.5	1.5	mA
		$V^+ = +5V, V_0 = 1.5V$		1.8	1.8	1.8	Max
		Both Amplifiers	1.1	1.7	1.7	1.7	mA
		V ⁺ = +15V, V _O = 7.5V		2	2	2	Max

LMC6082

AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}$ C, **Boldface** limits apply at the temperature extremes. V⁺ = 5V, V⁻ = 0V, V_{CM} = 1.5V, V_O = 2.5V and R_L > 1M unless otherwise specified.

			Тур	LMC6082AM	LMC6082AI	LMC6082I	
Symbol	Parameter	Conditions	(Note 5)	Limit	Limit	Limit	Units
				(Note 6)	(Note 6)	(Note 6)	
SR	Slew Rate	(Note 8)	1.5	0.8	0.8	0.8	V/µs
				0.5	0.6	0.6	Min
GBW	Gain-Bandwidth Product		1.3				MHz
φ _m	Phase Margin		50				Deg
	Amp-to-Amp Isolation	(Note 9)	140				dB
e _n	Input-Referred	F = 1 kHz	22				nV/√ Hz
	Voltage Noise						-
i _n	Input-Referred	F = 1 kHz	0.0002				pA∕v∕ Hz
	Current Noise						
T.H.D.	Total Harmonic	$F = 10 \text{ kHz}, A_V = -10$					
	Distortion	$R_L = 2 k\Omega, V_O = 8 V_{PP}$	0.01				%
		±5V Supply					

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of ±30 mA over long term may adversely affect reliability.

Note 3: The maximum power dissipation is a function of $T_{J(Max)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(Max)} - T_A)/\theta_{JA}$.

Note 4: Human body model, 1.5 k Ω in series with 100 pF.

Note 5: Typical values represent the most likely parametric norm.

Note 6: All limits are guaranteed by testing or statistical analysis.

Note 7: $V^+ = 15V$, $V_{CM} = 7.5V$ and R_L connected to 7.5V. For Sourcing tests, $7.5V \le V_O \le 11.5V$. For Sinking tests, $2.5V \le V_O \le 7.5V$.

Note 8: V⁺ = 15V. Connected as Voltage Follower with 10V step input. Number specified is the slower of the positive and negative slew rates.

Note 9: Input referred V⁺ = 15V and R_L = 100 k Ω connected to 7.5V. Each amp excited in turm with 1 kHz to produce V_O = 12 V_{PP}.

Note 10: For operating at elevated temperatures the device must be derated based on the thermal resistance θ_{JA} with $P_D = (T_J - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

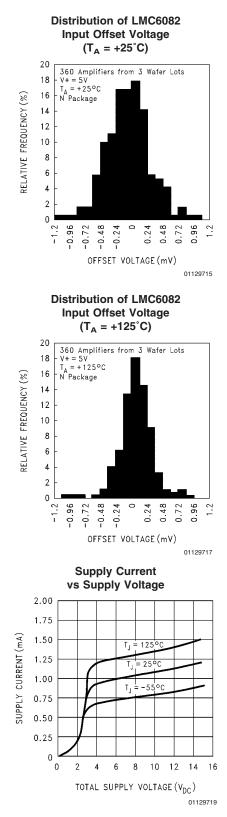
Note 11: Do not connect output to V^+ , when V^+ is greater than 13V or reliability will be adversely affected.

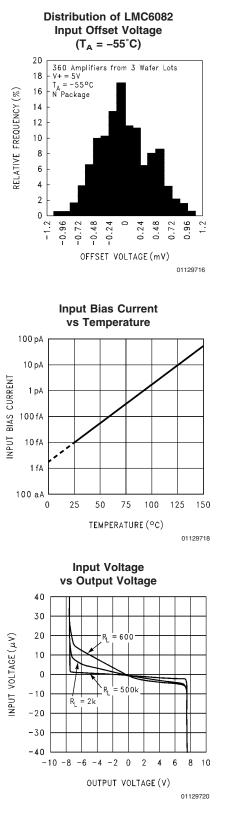
Note 12: All numbers apply for packages soldered directly into a PC board.



Typical Performance Characteristics

 $V_S = \pm 7.5V$, $T_A = 25^{\circ}C$, Unless otherwise specified

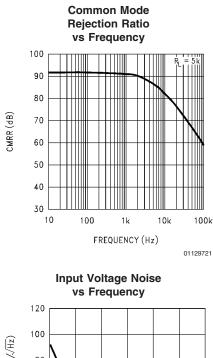


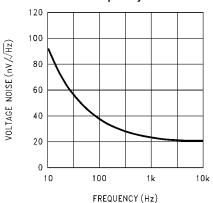


LMC6082

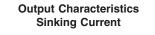
Typical Performance Characteristics $V_s = \pm 7.5V$, $T_A = 25^{\circ}C$, Unless otherwise

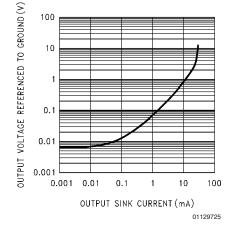
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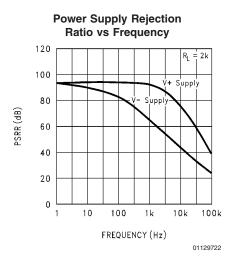




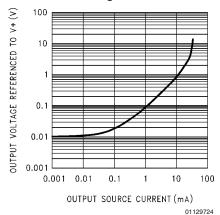




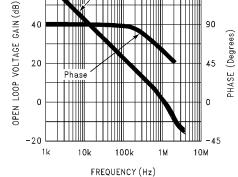




Output Characteristics Sourcing Current

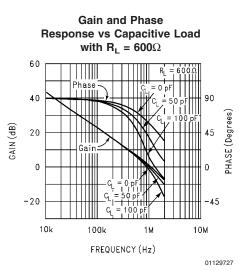


Gain and Phase Response vs Temperature (-55°C to +125°C)

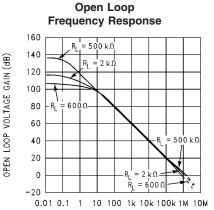


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Typical Performance Characteristics $V_s = \pm 7.5V$, $T_A = 25^{\circ}C$, Unless otherwise specified (Continued)



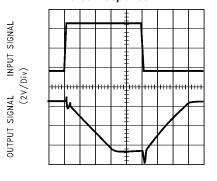




FREQUENCY (Hz)

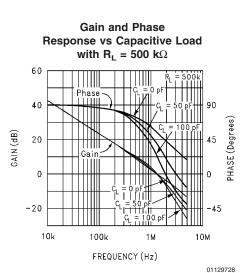
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Inverting Large Signal Pulse Response

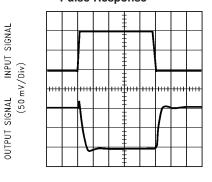


TIME(1 μ s/Div)

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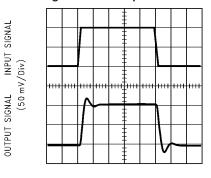


Inverting Small Signal Pulse Response



TIME (1 µs/Div) 01129730

Non-Inverting Small Signal Pulse Response



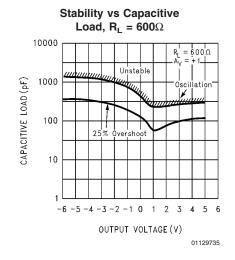
TIME(1μs/Div)

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ODDD SIGNAL INUT SIGNAL LADING LADING LADING SIGNAL PURSE RESPONSE





Applications Hints

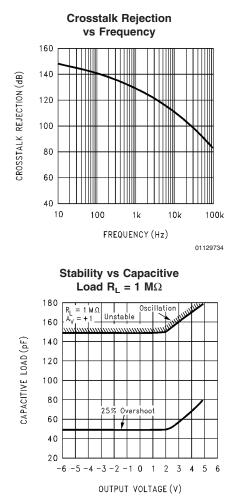
AMPLIFIER TOPOLOGY

The LMC6082 incorporates a novel op-amp design topology that enables it to maintain rail to rail output swing even when driving a large load. Instead of relying on a push-pull unity gain output buffer stage, the output stage is taken directly from the internal integrator, which provides both low output impedance and large gain. Special feed-forward compensation design techniques are incorporated to maintain stability over a wider range of operating conditions than traditional micropower op-amps. These features make the LMC6082 both easier to design with, and provide higher speed than products typically found in this ultra-low power class.

COMPENSATING FOR INPUT CAPACITANCE

It is quite common to use large values of feedback resistance for amplifiers with ultra-low input current, like the LMC6082.

Although the LMC6082 is highly stable over a wide range of operating conditions, certain precautions must be met to achieve the desired pulse response when a large feedback resistor is used. Large feedback resistors and even small values of input capacitance, due to transducers, photodiodes, and circuit board parasitics, reduce phase margins.



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When high input impedances are demanded, guarding of the LMC6082 is suggested. Guarding input lines will not only reduce leakage, but lowers stray input capacitance as well. (See *Printed-Circuit-Board Layout for High Impedance Work*).

The effect of input capacitance can be compensated for by adding a capacitor, C_f , around the feedback resistors (as in *Figure 1*) such that:

$$\frac{1}{2\pi R_1 C_{\text{IN}}} \ge \frac{1}{2\pi R_2 C_{\text{f}}}$$

or

$$R_1 C_{IN} \le R_2 C_f$$

Since it is often difficult to know the exact value of C_{IN} , C_f can be experimentally adjusted so that the desired pulse response is achieved. Refer to the LMC660 and LMC662 for a more detailed discussion on compensating for input capacitance.

Applications Hints (Continued)

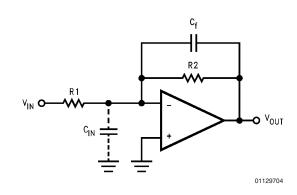


FIGURE 1. Cancelling the Effect of Input Capacitance

CAPACITIVE LOAD TOLERANCE

All rail-to-rail output swing operational amplifiers have voltage gain in the output stage. A compensation capacitor is normally included in this integrator stage. The frequency location of the dominant pole is affected by the resistive load on the amplifier. Capacitive load driving capability can be optimized by using an appropriate resistive load in parallel with the capacitive load (see typical curves).

Direct capacitive loading will reduce the phase margin of many op-amps. A pole in the feedback loop is created by the combination of the op-amp's output impedance and the capacitive load. This pole induces phase lag at the unity-gain crossover frequency of the amplifier resulting in either an oscillatory or underdamped pulse response. With a few external components, op amps can easily indirectly drive capacitive loads, as shown in *Figure 2*.

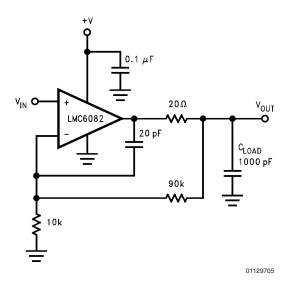


FIGURE 2. LMC6082 Noninverting Gain of 10 Amplifier, Compensated to Handle Capacitive Loads

In the circuit of *Figure 2*, R1 and C1 serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop.

Capacitive load driving capability is enhanced by using a pull up resistor to V⁺ *Figure 3.* Typically a pull up resistor conducting 500 μ A or more will significantly improve capacitive load responses. The value of the pull up resistor must be determined based on the current sinking capability of the amplifier with respect to the desired output swing. Open loop gain of the amplifier can also be affected by the pull up resistor (see Electrical Characteristics).

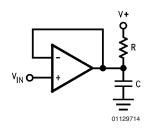
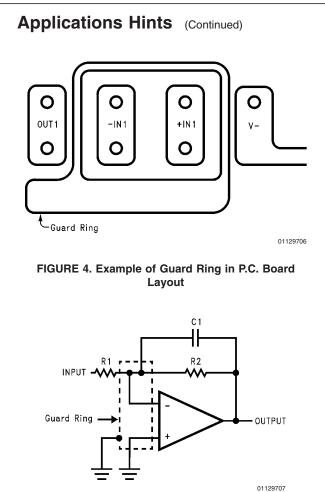


FIGURE 3. Compensating for Large Capacitive Loads with a Pull Up Resistor

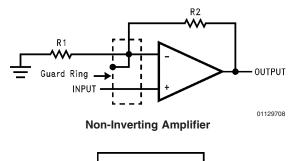
PRINTED-CIRCUIT-BOARD LAYOUT FOR HIGH-IMPEDANCE WORK

It is generally recognized that any circuit which must operate with less than 1000 pA of leakage current requires special layout of the PC board. When one wishes to take advantage of the ultra-low bias current of the LMC6082, typically less than 10 fA, it is essential to have an excellent layout. Fortunately, the techniques of obtaining low leakages are quite simple. First, the user must not ignore the surface leakage of the PC board, even though it may sometimes appear acceptably low, because under conditions of high humidity or dust or contamination, the surface leakage will be appreciable.

To minimize the effect of any surface leakage, lay out a ring of foil completely surrounding the LMC6082's inputs and the terminals of capacitors, diodes, conductors, resistors, relay terminals, etc. connected to the op-amp's inputs, as in Figure 4. To have a significant effect, guard rings should be placed on both the top and bottom of the PC board. This PC foil must then be connected to a voltage which is at the same voltage as the amplifier inputs, since no leakage current can flow between two points at the same potential. For example, a PC board trace-to-pad resistance of $10^{12}\Omega$, which is normally considered a very large resistance, could leak 5 pA if the trace were a 5V bus adjacent to the pad of the input. This would cause a 100 times degradation from the LMC6082's actual performance. However, if a guard ring is held within 5 mV of the inputs, then even a resistance of $10^{11}\Omega$ would cause only 0.05 pA of leakage current. See Figure 5 for typical connections of guard rings for standard op-amp configurations.



Inverting Amplifier



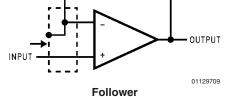
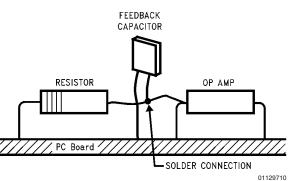


FIGURE 5. Typical Connections of Guard Rings

The designer should be aware that when it is inappropriate to lay out a PC board for the sake of just a few circuits, there is another technique which is even better than a guard ring on a PC board: Don't insert the amplifier's input pin into the board at all, but bend it up in the air and use only air as an insulator. Air is an excellent insulator. In this case you may have to forego some of the advantages of PC board construction, but the advantages are sometimes well worth the effort of using point-to-point up-in-the-air wiring. See *Figure 6*.

Latchup

CMOS devices tend to be susceptible to latchup due to their internal parasitic SCR effects. The (I/O) input and output pins look similar to the gate of the SCR. There is a minimum current required to trigger the SCR gate lead. The LMC6062 and LMC6082 are designed to withstand 100 mA surge current on the I/O pins. Some resistive method should be used to isolate any capacitance from supplying excess current to the I/O pins. In addition, like an SCR, there is a minimum holding current for any latchup mode. Limiting current to the supply pins will also inhibit latchup susceptibility.



(Input pins are lifted out of PC board and soldered directly to components. All other pins connected to PC board).

FIGURE 6. Air Wiring

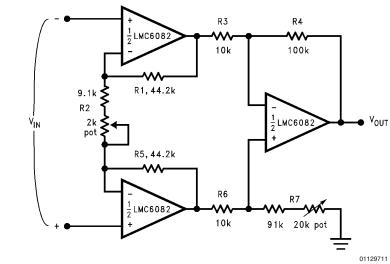
Typical Single-Supply Applications

$(V^+ = 5.0 V_{DC})$

The extremely high input impedance, and low power consumption, of the LMC6082 make it ideal for applications that require battery-powered instrumentation amplifiers. Examples of these types of applications are hand-held pH probes, analytic medical instruments, magnetic field detectors, gas detectors, and silicon based pressure transducers.

Figure 7 shows an instrumentation amplifier that features high differential and common mode input resistance (>10¹⁴Ω), 0.01% gain accuracy at A_V = 1000, excellent CMRR with 1 kΩ imbalance in bridge source resistance. Input current is less than 100 fA and offset drift is less than 2.5 μ V/°C. R₂ provides a simple means of adjusting gain over a wide range without degrading CMRR. R₇ is an initial trim used to maximize CMRR without using super precision matched resistors. For good CMRR over temperature, low drift resistors should be used.

Typical Single-Supply Applications (Continued)



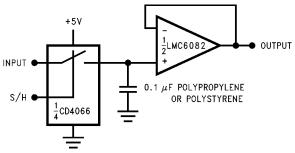
If $R_1 = R_5$, $R_3 = R_6$, and $R_4 = R_7$; then

$$\frac{V_{OUT}}{V_{IN}} = \frac{R_2 + 2R_1}{R_2} \times \frac{R_4}{R_3}$$

 $\therefore A_V \approx$ 100 for circuit shown (R_2 = 9.822k).



Typical Single-Supply Applications $(V^+ = 5.0 V_{DC})$

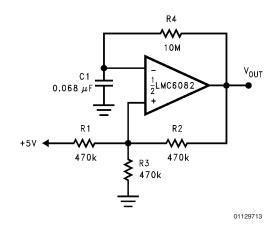


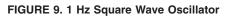
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LMC6082

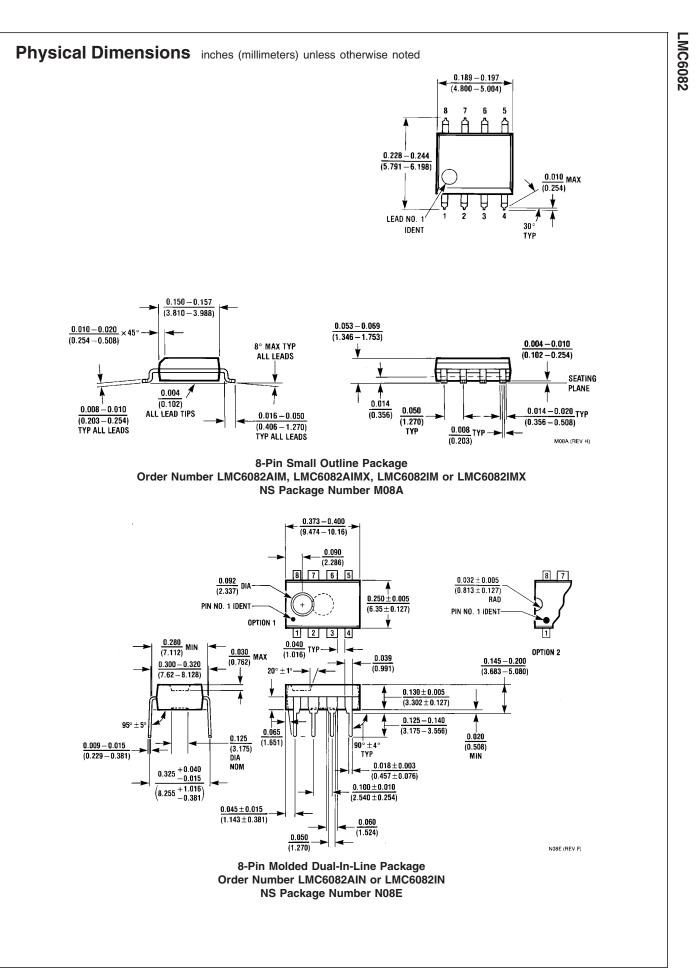
Typical Single-Supply Applications (V⁺ = 5.0 V_{DC}) (Continued)





Ordering Information

Package	Temperatu	ire Range	NSC	Transport		
	Military	Industrial	Drawing	Media		
	–55°C to +125°C	–40°C to +85°C				
8-Pin		LMC6082AIN	N08E	Rail		
Molded DIP		LMC6082IN				
8-Pin		LMC6082AIM,	M08A	Rail		
		LMC6082AIMX,	IVIUOA			
Small Outline		LMC6082IM,		Tape and Reel		
		LMC6082IMX				
For MIL-STD-883C qualified products, please contact your local National						
Semiconductor Sales Office or Distributor for availability and specification						
information.	information.					



Notes

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- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

BANNED SUBSTANCE COMPLIANCE

National Semiconductor certifies that the products and packing materials meet the provisions of the Customer Products Stewardship Specification (CSP-9-111C2) and the Banned Substances and Materials of Interest Specification (CSP-9-111S2) and contain no "Banned Substances" as defined in CSP-9-111S2.

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